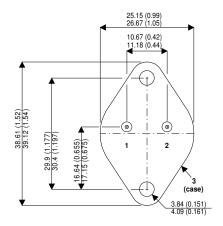
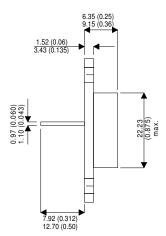


BDY26B

MECHANICAL DATA

Dimensions in mm (inches)





HIGH CURRENT NPN SILICON TRANSISTOR

FEATURES

- HIGH SWITCHING CURRENTS
- HIGH RELIABILITY
- CECC SCREENING OPTIONS
- SPACE QUALITY LEVELS OPTIONS
- JAN LEVEL SCREENING OPTIONS

APPLICATIONS

- SWITCHING REGULATORS
- LINEAR APPLICATIONS

TO3 (TO204AA)

Pin 1 = Base Pin 2 = Emitter Case = Collector

ABSOLUTE MAXIMUM RATINGS

$T_{CASE} = 25$	$5^{\circ}\mathrm{C}$ unless otherwise state		
V_{CBO}	Collector - Base Voltage		300V
$V_{\sf CEO}$	Collector - Emitter Voltage		180V
V_{EBO}	Emitter – Base Voltage	10V	
I_{C}	Continuous Collector Current		6A
I_{B}	Base Current		3A
P_{tot}	Total Power Dissipation at	$T_{case} = 25$ °C	50W
		Derate above 25 °C	0.29 W/°C
T_J	Junction Temperature		200℃
T_{stg}	Storage Temperature		-65 to 200 <i>°</i> C

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THERMAL CHARACTERISTICS	Max	Unit
R _{th} j-case Thermal resistance to case	3.5	°C/W

ELECTRICAL CHARACTERISTICS (T_{case}=25 ℃ unless otherwise stated)

Parameter		Test Conditions		Min.	Тур.	Max.	Unit
I _{CEO}	Collector Cut-Off Current	V _{CE} = 140V	$I_B = 0$			1.0	
I _{CES}	Collector Cut-Off Current	V _{CE} = 180V	V _{BE} = 0			1.0	mA
I _{EBO}	Emitter Cut-Off Current	V _{EB} = 10V	I _C = 0			1.0	
V _{(BR)CEO} *	Collector-Emitter Breakdown Voltage	$I_C = 50mA$	$I_B = 0$	180			
V _{(BR)CBO} *	Collector-Base Breakdown Voltage	$I_C = 3mA$		300			V
V _{CE(sat)} *	Collector-Emitter Saturation Voltage	I _C = 2.0A	$I_B = 0.25A$			0.6	V
V _{BE(sat)} *	Base-Emitter Saturation Voltage	I _C = 2.0A	$I_{B} = 0.25A$			1.2	
h _{FE} *	Forward-current transfer ratio	I _C = 1.0A	$V_{CE} = 4.0V$		65		
		I _C = 2.0A	$V_{CE} = 4.0V$	30	45	90	

DYNAMIC CHARACTERISTICS

C _{obo}	Output Capacitance	$I_E = 0$ f = 1.0MHz	V _{CB} = 10V		65	120	pF
F _T	Transition Frequency	$I_{C} = 0.5A$ $f = 10.0MHz$	V _{CE} = 15V	10			MHz
T _{on}	Turn-on time	I _C = 5.0A	I _{B1} = 1.0A			1.0	110
T_{off}	Turn-off time	I _C = 5.0A	$I_{B1} = -I_{B2} = 1.0A$			3.5	μs

^{*} Pulse test t_p = 300 μ s, δ < 2%

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Semelab plc. Telephone +44(0)1455 556565. Fax +44(0)1455 552612. E-mail: sales@semelab.co.uk Website: http://www.semelab.co.uk